

View Online at <https://aerobasegroup.com/nsn/5961-00-824-3884>

Inclosure Material:

Plastic all semiconductor device diode

Overall Length:

0.425 inches all semiconductor device diode and 0.465 inches all semiconductor device diode

Terminal Length:

0.900 inches all semiconductor device diode

Overall Height:

0.165 inches all semiconductor device diode and 0.200 inches all semiconductor device diode

Overall Width:

0.300 inches all semiconductor device diode

Internal Configuration:

Junction contact all semiconductor device diode

Internal Junction Configuration:

Pn all semiconductor device diode

Component Function Relationship:

Matched

Component Name And Quantity:

4 semiconductor device diode

Mounting Method:

Terminal all semiconductor device diode

Semiconductor Material:

Silicon all semiconductor device diode

Voltage Rating In Volts Per Characteristic:

50.0 working peak reverse voltage, peak total value all semiconductor device diode

Current Rating Per Characteristic:

225.00 milliamperes all primaries preset all semiconductor device diode and 75.00 milliamperes drain current megahertz all semiconductor device diode and 500.00 milliamperes collector current, dc preset all semiconductor device diode and 2.00 amperes forward current, dc nanoamperes all semiconductor device diode

Maximum Operating Temperature Per Measurement Point:

150.0 degrees celsius ambient air all semiconductor device diode

Special Features:

C/o 2 pair matched w/in 20 milliamps fwd current, ea pair in pkg as described.

Terminal Type And Quantity:

2 uninsulated wire lead all semiconductor device diode

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fig:

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